## 16M-BIT MASK-PROGRAMMABLE ROM 2M-WORD BY 8-BIT (BYTE MODE)/1M-WORD BY 16-BIT (WORD MODE)

## Description

The $\mu$ PD23C16000W is a $16,777,216$ bits mask-programmable ROM. The word organization is selectable (BYTE mode: 2,097,152 words by 8 bits, WORD mode: 1,048,576 words by 16 bits).

The active levels of OE (Output Enable Input) can be selected with mask-option.
The $\mu$ PD23C16000W are packed in 42-pin plastic DIP, 44-pin plastic SOP, 48-pin plastic TSOP (I) and 44-pin plastic TSOP (II).

## Features

- Word organization

2,097,152 words by 8 bits (BYTE mode)
$1,048,576$ words by 16 bits (WORD mode)

- Access time 120 ns (MAX.)
- Low current consumption

Active .............. 70 mA (MAX.)
Standby ........... $100 \mu \mathrm{~A}$ (MAX.) (CMOS level input)

## Ordering Information

| Part Number | Package |
| :--- | :--- |
| $\mu$ PD23C16000WCZ-XXX | 42-pin Plastic DIP $(600$ mil $)$ |
| $\mu$ PD23C16000WGX-XXX | 44-pin Plastic SOP $(600 \mathrm{mil})$ |
| $\mu$ PD23C16000WGY-XXX-MJH | 48-pin Plastic TSOP $(I)(12 \times 18 \mathrm{~mm})$ (Normal bent) |
| $\mu$ PD23C16000WGY-XXX-MKH | 48-pin Plastic TSOP (I) $(12 \times 18 \mathrm{~mm})$ (Reverse bent) |
| $\mu$ PD23C16000WG5-XXX-7JF | 44-pin Plastic TSOP (II) $(400$ mil) (Normal bent) |

(XXX: ROM code suffix No.)

The information in this document is subject to change without notice.

## * Pin Configuration (Marking Side)



| A0-A19 | Address inputs |
| :---: | :---: |
| O0-07, O8-01 | Data outputs |
| O15/A-1 | Data 15 ouput (WORD mode)/LSB address input (BYTE mode) |
| WORD/BYTE | Mode select |
| $\overline{C E}$ | Chip enable |
| $\overline{\mathrm{OE}} / \mathrm{OE}$ | Output enable |
| Vcc | Supply voltage |
| GND | Ground |
| NC ${ }^{\text {Note } 1}$ | No connection |
| IC ${ }^{\text {Note } 2}$ | Internal connection |
| DC | Don't care |

Notes 1. Some signal can be applied because this pin is not connected to the inside of the chip.
2. Leave this pin unconnected or connect to GND.

48-pin Plastic TSOP (I) ( $12 \times 18 \mathrm{~mm}$ ) (Reverse bent) [ $\mu$ PD23C16000WGY-MJH]


48-pin Plastic TSOP (I) ( $12 \times 18 \mathrm{~mm}$ ) (Reverse bent)
[ $\mu$ PD23C16000WGY-MKH]


44-pin Plastic TSOP (II) ( 400 mil ) (Normal bent) [ $\mu$ PD23C16000WG5-7JF]


## Input/Output Pin Functions

| Pin name | Input/ <br> Output | Function |
| :--- | :--- | :--- | :--- |

Block Diagram


## Mask Option

The active levels of output enable pin ( $\overline{\mathrm{OE} / \mathrm{OE} / \mathrm{DC}) \text { are mask programmable and optional, and can be selected from }}$ among " 0 " " 1 " " $\times$ " shown in the table below.

| Option | $\overline{\mathrm{OE}} / \mathrm{OE} / \mathrm{DC}$ | OE active level |
| :---: | :---: | :---: |
| 0 | $\overline{\mathrm{OE}}$ | L |
| 1 | OE | H |
| $\times$ | DC | Don't care |

Operation modes for each option are shown in the tables below.

Operation mode (Option: 0)

| CE | $\overline{\mathrm{OE}}$ | Mode | Output state |
| :---: | :---: | :---: | :--- |
| L | L | Active | Data out |
|  | H |  | High impedance |
| H | H or L | Standby | High impedance |

Operation mode (Option: 1)

| $\overline{\mathrm{CE}}$ | OE | Mode | Output state |
| :---: | :---: | :--- | :--- |
| L | L | Active | High impedance |
|  | H |  |  |
| H | H or L | Standby | High impedance |

Operation mode (Option: $\times$ )

| $\overline{\mathrm{CE}}$ | DC | Mode | Output state |
| :---: | :---: | :---: | :--- |
| $L$ | H or $L$ | Active | Data out |
| $H$ | H or $L$ | Standby | High impedance |

Remark L: Low level input
H: High level input

## Electrical Specifications

## Absolute Maximum Ratings

| Parameter | Symbol | Conditions | Ratings | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{cc}}$ |  | -0.3 to +7.0 | V |
| Input voltage | $\mathrm{V}_{\mathrm{I}}$ |  | -0.3 to $\mathrm{Vcc}+0.3$ | V |
| Output voltage | $\mathrm{Vo}_{\mathrm{cc}}$ |  | -0.3 to $\mathrm{Vcc}+0.3$ | $\mathrm{~V}^{\mathrm{V}}$ |
| Operating ambient temperature | $\mathrm{T}_{\mathrm{A}}$ |  | -10 to +70 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $\mathrm{T}_{\mathrm{stg}}$ |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Caution Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational sections of this specification. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Capacitance ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Test conditions | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input capacitance | CI | $\mathrm{f}=1 \mathrm{MHz}$ |  |  | 10 | pF |
| Output capacitance | Co |  |  |  | 12 | pF |

DC Characteristics ( $\mathrm{T}_{\mathrm{A}}=-10$ to $+70^{\circ} \mathrm{C}, \mathrm{Vcc}=5 \mathrm{~V} \pm 10 \%$ )

| Parameter | Symbol | Test conditions | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| High level input voltage | $\mathrm{V}_{\mathrm{H}}$ |  | 2.2 |  | $\mathrm{Vcc}+0.3$ | V |
| Low level input voltage | VIL |  | -0.3 |  | +0.8 | V |
| High level output voltage | Vor1 | Іон $=-400 \mu \mathrm{~A}$ | 2.4 |  |  | V |
|  | Vон2 | $\mathrm{IOH}=-100 \mu \mathrm{~A}$ | V cc -0.5 |  |  |  |
| Low level output voltage | VoL | $\mathrm{loL}=2.1 \mathrm{~mA}$ |  |  | 0.4 | V |
| Input leakage current | lı | $\mathrm{V}_{1}=0$ to Vcc | -10 |  | +10 | $\mu \mathrm{A}$ |
| Output leakage current | ILo | $\mathrm{V}_{\mathrm{o}}=0$ to Vcc, Chip deselected | -10 |  | +10 | $\mu \mathrm{A}$ |
| Power supply current | lc 01 | $\overline{\mathrm{CE}}=\mathrm{V}$ IL (Active mode), $\mathrm{lo}=0 \mathrm{~mA}$ |  |  | 70 | mA |
| Standby current | Icco | $\overline{\mathrm{CE}}=\mathrm{V}_{\text {IH }}$ (Standby mode) |  |  | 1.5 | mA |
|  | Icc3 | $\overline{\mathrm{CE}}=\mathrm{Vcc}-0.2 \mathrm{~V}$ (Standby mode) |  |  | 100 | $\mu \mathrm{A}$ |

AC Characteristics ( $\mathrm{T}_{\mathrm{A}}=-10$ to $+70^{\circ} \mathrm{C}, \mathrm{Vcc}=5 \mathrm{~V} \pm 10 \%$ )

| Parameter | Symbol | Test conditions | MIN. | TYP. | MAX. | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Address access time | tacc |  |  |  | 120 | ns |
| Chip enable access time | tce |  |  |  | 120 | ns |
| Output enable access time | toE |  |  |  | 50 | ns |
| Output hold time | toH |  | 0 |  |  | ns |
| Output disable time | tDF |  | 0 |  | 25 | ns |
| WORD/BYTE access time | twb |  |  |  | 120 | ns |

Remark tof is the time from inactivation of $\overline{\mathrm{CE}}$ or $\overline{\mathrm{OE}} / \mathrm{OE}$ to high-impedance state output.

## AC Test Conditions

Input waveform (Rise/Fall time $\leq 5 \mathrm{~ns}$ )


Output waveform


Output load

1 TTL + 100 pF

Read Cycle Timing Chart


Notes 1. During WORD mode, $\mathrm{A}-1$ is O 15.
2. tDF is specified when the one of $\overline{C E}, \overline{O E}$ or $O E$ is inactivated.
3. During BYTE mode, O8 to O14 are high impedance and O15 is $\mathrm{A}-1$.

WORD/BYTE Switch Timing Chart


Remark $\overline{\mathrm{OE}} / \mathrm{OE}, \overline{\mathrm{CE}}$ : Active.

## Notice of change in 48-pin TSOP (I) standoff height

We are changing the 48-pin TSOP (I) standoff height $0.05 \pm 0.05 \mathrm{~mm}$ (low standoff height) to $0.1 \pm 0.05 \mathrm{~mm}$ (high standoff height). Each lot version is identified by the fifth character of the lot number.

Difference between high standoff height and low standoff height

## Detail of lead end

Normal bent
High standoff height: $Q=0.1 \pm 0.05 \mathrm{~mm}$
Low standoff height: $Q=0.05 \pm 0.05 \mathrm{~mm}$

## Identification of each lot version

Each lot version is identified by the fifth character of the lot number.

| Fifth character of the lot number | Lot version | Standoff height |
| :---: | :---: | :---: |
| L | L version | $0.1 \pm 0.05 \mathrm{~mm}$ (High standoff height) |
| K | K version | $0.05 \pm 0.05 \mathrm{~mm}$ (Low standoff height) |

## Marking Example



## * Package Drawings

42PIN PLASTIC DIP (600 mil)


## notes

1) Each lead centerline is located within 0.25 mm ( 0.01 inch ) of its true position (T.P.) at maximum material condition.
2) Item "K" to center of leads when formed parallel.

| ITEM | MILLIMETERS | INCHES |
| :---: | :---: | :---: |
| A | 55.88 MAX. | 2.200 MAX. |
| B | 2.54 MAX. | 0.100 MAX. |
| C | 2.54 (T.P.) | 0.100 (T.P.) |
| D | $0.50 \pm 0.10$ | $0.020_{-0.005}^{+0.004}$ |
| F | 1.2 MIN. | 0.047 MIN . |
| G | $3.6 \pm 0.3$ | $0.142 \pm 0.012$ |
| H | 0.51 MIN . | 0.020 MIN . |
| I | 4.31 MAX. | 0.170 MAX. |
| J | 5.72 MAX. | 0.226 MAX. |
| K | 15.24 (T.P.) | 0.600 (T.P.) |
| L | 13.2 | 0.520 |
| M | $0.25_{-0.05}^{+0.10}$ | $0.010_{-0.003}^{+0.004}$ |
| N | 0.25 | 0.01 |
| R | 0~15 | 0~15 ${ }^{\circ}$ |
| P42C-100-600A,B-1 |  |  |

## 44 PIN PLASTIC SOP (600 mil)



## NOTE

1. Controlling dimension - millimeter.
2. Each lead centerline is located within $0.12 \mathrm{~mm}(0.005 \mathrm{inch})$ of its true position (T.P.) at maximum material condition.

| ITEM | MILLIMETERS | INCHES |
| :---: | :---: | :---: |
| A | $27.83{ }_{-0.05}^{+0.4}$ | $1.096{ }_{-0.003}^{+0.016}$ |
| B | 0.78 MAX . | 0.031 MAX. |
| C | 1.27 (T.P.) | 0.050 (T.P.) |
| D | $0.42_{-0.07}^{+0.08}$ | $0.017_{-0.004}^{+0.003}$ |
| E | $0.15 \pm 0.1$ | $0.006 \pm 0.004$ |
| F | 3.0 MAX. | 0.119 MAX. |
| G | $2.7 \pm 0.05$ | $0.106_{-0.002}^{+0.003}$ |
| H | $16.04 \pm 0.3$ | $0.631_{-0.012}^{+0.013}$ |
| 1 | $13.24 \pm 0.1$ | $0.521_{-0.004}^{+0.005}$ |
| J | $1.4 \pm 0.2$ | $0.055 \pm 0.008$ |
| K | $0.22_{-0.07}^{+0.08}$ | $0.009_{-0.004}^{+0.003}$ |
| L | $0.8 \pm 0.2$ | $0.031_{-0.008}^{+0.009}$ |
| M | 0.12 | 0.005 |
| N | 0.10 | 0.004 |
| P | $3^{\circ}{ }_{-3^{\circ}}{ }^{\circ}$ | $3^{\circ}{ }_{-3^{\circ}}{ }^{\circ}$ |

## L Version: High standoff height

## 48 PIN PLASTIC TSOP (I) (12×18)



## NOTES

1. Controlling dimension - Millimeter.
2. Each lead centerline is located within 0.10 mm ( 0.004 inch ) of its true position (T.P.) at maximum material condition.
3. "A" excludes mold flash. (Includes mold flash : 12.4 mm MAX. <0.489 inch MAX.>)
detail of lead end


| ITEM | MILLIMETERS | INCHES |
| :---: | :---: | :---: |
| A | $12.0 \pm 0.1$ | $0.472_{-0.004}^{+0.005}$ |
| B | 0.45 MAX. | 0.018 MAX. |
| C | 0.5 (T.P.) | 0.020 (T.P.) |
| D | $0.22 \pm 0.05$ | $0.009_{-0.003}^{+0.002}$ |
| E | $0.1 \pm 0.05$ | $0.004 \pm 0.002$ |
| F | 1.2 MAX. | 0.048 MAX. |
| G | $1.0 \pm 0.05$ | $0.039+0.003$ |
| I | $16.4 \pm 0.1$ | $0.646{ }_{-0.005}^{+0.004}$ |
| J | $0.8 \pm 0.2$ | 0.031 ${ }_{-0.008}^{+0.009}$ |
| K | $0.145 \pm 0.05$ | $0.006+0.002$ |
| L | 0.5 | 0.020 |
| M | 0.10 | 0.004 |
| N | 0.10 | 0.004 |
| P | $18.0 \pm 0.2$ | $0.709_{-0.009}^{+0.008}$ |
| Q | $3^{\circ}+{ }_{-3}{ }^{\circ}$ | $3^{\circ}+{ }_{-3}{ }^{\circ}$ |
| R | 0.25 | 0.010 |
| S | $0.60 \pm 0.15$ | $0.024_{-0.007}^{+0.006}$ |
|  |  | S48GY-50-MJH |

## L Version: High standoff height

## 48 PIN PLASTIC TSOP (I) (12×18)



## NOTES

1. Controlling dimension - Millimeter.
2. Each lead centerline is located within 0.10 mm ( 0.004 inch ) of its true position (T.P.) at maximum material condition.
3. "A" excludes mold flash. (Includes mold flash : 12.4 mm MAX. <0.489 inch MAX.>)

| ITEM | MILLIMETERS | INCHES |
| :---: | :--- | :--- |
| A | $12.0 \pm 0.1$ | $0.472_{-0.004}^{+0.005}$ |
| B | 0.45 MAX. | 0.018 MAX. |
| C | 0.5 (T.P.) | 0.020 (T.P.) |
| D | $0.22 \pm 0.05$ | $0.009_{-0.003}^{+0.002}$ |
| E | $0.1 \pm 0.05$ | $0.004 \pm 0.002$ |
| F | 1.2 MAX. | 0.048 MAX. |
| G | $1.0 \pm 0.05$ | $0.039_{-0.002}^{+0.003}$ |
| I | $16.4 \pm 0.1$ | $0.646_{-0.005}^{+0.004}$ |
| J | $0.8 \pm 0.2$ | $0.031_{-0.008}^{+0.009}$ |
| K | $0.145 \pm 0.05$ | $0.006_{-0.003}^{+0.002}$ |
| L | 0.5 | 0.020 |
| M | 0.10 | 0.004 |
| N | 0.10 | 0.004 |
| P | $18.0 \pm 0.2$ | $0.709_{-0.009}^{+0.008}$ |
| Q | $3^{\circ+5^{\circ}}$ | $3^{\circ+5^{\circ}}$  <br> R 0.25 |
| S | $0.60 \pm 0.15$ | $0.024_{-0.007}^{+0.006}$ |
|  | S48GY-50-MKH1 |  |

## K Version: Low standoff height

## 48 PIN PLASTIC TSOP (I) (12x18)



## NOTES

1. Controlling dimension - millimeter.
2. Each lead centerline is located within 0.08 mm ( 0.003 inch ) of its true position (T.P.) at maximum material condition.
3. "A" excludes mold flash. (Includes mold flash: 12.4 mm MAX. <0.489 inch MAX.>)

| ITEM | MILLIMETERS | INCHES |
| :---: | :---: | :--- |
| A | $12.0 \pm 0.1$ | $0.472_{-0.004}^{+0.005}$ |
| B | 0.45 MAX. | 0.018 MAX. |
| C | 0.5 (T.P.) | 0.020 (T.P.) |
| D | $0.22_{-0.07}^{+0.08}$ | $0.009_{-0.004}^{+0.003}$ |
| G | 0.97 | 0.038 |
| H | $17.0 \pm 0.2$ | $0.669_{-0.008}^{+0.009}$ |
| I | $16.4 \pm 0.1$ | $0.646_{-0.005}^{+0.004}$ |
| J | $0.8 \pm 0.2$ | $0.031_{-0.008}^{+0.009}$ |
| K | $0.145_{-0.055}^{+0.03}$ | $0.006_{-0.003}^{+0.001}$ |
| L | $0.5 \pm 0.1$ | $0.020_{-0.005}^{+0.004}$ |
| M | 0.08 | 0.003 |
| N | 0.10 | 0.004 |
| P | $18.0 \pm 0.2$ | $0.709_{-0.009}^{+0.008}$ |
| Q | $0.05 \pm 0.05$ | $0.002^{ \pm 0.002}$ |
| R | $2^{\circ}+4^{\circ}$ | $2^{\circ}+4^{\circ}$ |
| S | $1.02 \pm 0.08$ | $0.040_{-0.000}^{+0.004}$ |
|  | S48GY-50-MJH-3 |  |

## K Version: Low standoff height

## 48 PIN PLASTIC TSOP (I) (12×18)



NOTES

1. Controlling dimension - millimeter.
2. Each lead centerline is located within $0.08 \mathrm{~mm}(0.003 \mathrm{inch})$ of its true position (T.P.) at maximum material condition.
3. "A" excludes mold flash. (Includes mold flash: 12.4 mm MAX. <0.489 inch MAX.>)

| ITEM | MILLIMETERS | INCHES |
| :---: | :---: | :--- |
| A | $12.0 \pm 0.1$ | $0.472_{-0.004}^{+0.005}$ |
| B | 0.45 MAX. | 0.018 MAX. |
| C | 0.5 (T.P.) | 0.020 (T.P.) |
| D | $0.22_{-0.07}^{+0.08}$ | $0.009_{-0.004}^{+0.003}$ |
| G | 0.97 | 0.038 |
| H | $17.0 \pm 0.2$ | $0.669_{-0.008}^{+0.009}$ |
| I | $16.4 \pm 0.1$ | $0.646_{-0.005}^{+0.004}$ |
| J | $0.8 \pm 0.2$ | $0.031_{-0.008}^{+0.009}$ |
| K | $0.145_{-0.055}^{+0.03}$ | $0.006_{-0.003}^{+0.001}$ |
| L | $0.5 \pm 0.1$ | $0.020_{-0.005}^{+0.004}$ |
| M | 0.08 | 0.003 |
| N | 0.10 | 0.004 |
| P | $18.0 \pm 0.2$ | $0.709_{-0.009}^{+0.008}$ |
| Q | $0.05 \pm 0.05$ | $0.002^{ \pm 0.002}$ |
| R | $2_{-2}^{\circ+4^{\circ}}$ | $2_{-2^{\circ}}^{\circ}$ |
| S | $1.02 \pm 0.08$ | $0.040_{-0.004}^{+0.004}$ |
|  | S48GY-50-MKH-3 |  |

## 44 PIN PLASTIC TSOP(II) (400 mil)


detail of lead end


| ITEM | MILLIMETERS | INCHES |
| :---: | :---: | :---: |
| A | 18.63 MAX. | 0.734 MAX. |
| B | 0.93 MAX. | 0.037 MAX. |
| C | 0.8 (T.P.) | 0.031 (T.P.) |
| D | $0.32_{-0.07}^{+0.08}$ | $0.013 \pm 0.003$ |
| E | $0.1 \pm 0.05$ | $0.004 \pm 0.002$ |
| F | 1.2 MAX. | 0.048 MAX. |
| G | 0.97 | 0.038 |
| H | $11.76 \pm 0.2$ | $0.463 \pm 0.008$ |
| I | $10.16 \pm 0.1$ | $0.400 \pm 0.004$ |
| $J$ | $0.8 \pm 0.2$ | $0.031_{-0.008}^{+0.009}$ |
| K | $0.145_{-0.015}^{+0.025}$ | $0.006 \pm 0.001$ |
| L | $0.5 \pm 0.1$ | $0.020_{-0.005}^{+0.004}$ |
| M | 0.13 | 0.005 |
| N | 0.10 | 0.004 |
| P | $3^{\circ}+7_{-3}{ }^{\circ}$ | $3^{\circ}+7^{\circ}{ }^{\circ}$ |
|  |  | S44G5-80-7JF |

## Recommended Soldering Conditions

The following conditions (see table below) must be met when soldering the $\mu$ PD23C16000W.
For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (C10535E).

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

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Types of Surface Mount Device
\muPD23C16000WGX : 44-pin Plastic SOP (600 mil)
\muPD23C16000WGY-MJH : 48-pin Plastic TSOP (I) (12\times18 mm) (Normal bent)
\muPD23C16000WGY-MKH: 48-pin Plastic TSOP (I) (12\times18 mm) (Reverse bent)
\muPD23C16000WG5-7JF : 44-pin Plastic TSOP (II) (400 mil) (Normal bent)
```

Please consult with our sales offices.

## Type of Through Hole Mount Device

$\mu$ PD23C16000WCZ : 42-pin Plastic DIP (600 mil)

| Soldering process | Soldering conditions |
| :--- | :--- |
| Wave soldering <br> (Only to leads) | Solder temperature: $260{ }^{\circ} \mathrm{C}$ or below, <br> Flow time: 10 seconds or below |
| Partial heating method | Terminal temperature: $300{ }^{\circ} \mathrm{C}$ or below, <br> Time: 3 seconds or below (Per one lead) |

## Caution Do not jet molten solder on the surface of package.

[MEMO]
[MEMO]
[MEMO]

## NOTES FOR CMOS DEVICES

## (1) PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

## (2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to Vod or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

## (3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

## [MEMO]


#### Abstract

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
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Anti-radioactive design is not implemented in this product.

